# Transport signatures of van Hove singularities in mesoscopic twisted bilayer graphene 00

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### Introduction and motivation

**Twisted bilayer graphene** is a fascinating

- contains low-energy, remarkably flat

- is a low-temperature superconductor

- exhibits strongly correlated phases

- its quasi-flat bands contain special

singularities (van Hove singularities)

which are tunable to the Fermi level.

with a relative angle between them. At

certain "magic" twist angles it has

extraordinary properties [1-3]:

bands in the spectrum

material made of two graphene layers stacked



Graphene layers

Mac

van Hove singularities are saddle points in the energy dispersion  $\rightarrow \vec{\nabla} E(\mathbf{k}) = 0$  $\rightarrow$  the Density of States diverges  $\rightarrow$  enhanced electron correlation

**Motivation:** it remains an outstanding challenge to understand the effects of quasi-flat bands, VHSs and the rich variety of possible Fermi surface topologies on the quantum transport in mesoscopic TBLG samples. Most research to date has focused on observables in the thermodynamic limit and on transport in macroscopic samples in the semiclassical regime

# Model and four-terminal transport setup



#### Tight-binding model

- Intralayer: Only nearest-neighbour hoppings
- Interlayer: Minimal model with exponential decay [4]:

$$H_{12} = -\sum_{\langle i,j \rangle \sigma} t'(r_{ij}) c_{i,2,\sigma}^{\dagger} c_{j,1,\sigma} + \text{h.c.}$$
$$t'(r) = V_{pp\sigma}^{0} e^{-\left(\sqrt{r^{2} + d_{0}^{2}} - d_{0}\right)/\lambda} \frac{d_{0}^{2}}{r^{2} + d_{0}^{2}}$$

#### Four-terminal setup for conductance calculations



**Our contribution:** we study the correspondence of four-terminal conductance and the Fermi surface topology as a function of the twist angle, pressure, and energy in mesoscopic samples

- Channel 1 => 2: Wide-junction, through the same graphene layer (top)
- Channel 3 => 4: Narrow-junction, through the same graphene layer (bottom)
- Channels  $1 \Rightarrow 4 \& 3 \Rightarrow 2$ : Interlayer junctions, terminals in different layers



# Signatures of VHS in the conductance



# Conclusions

• the low-energy electron transport in twisted bilayer graphene is affected by several factors: the flattening of the bands, van Hove singularities, the size of the system and non-singular crossing points

- the system is highly sensitive to external parameters => possible applications in high-frequency devices and sensitive detectors
- the system shows oscillations with an unusually large amplitude in the conductance with system size
- van Hove singularities give rise to sharp, non-linear increases in the conductance

## References

[1] Suarez et al., PRB **82**, 121407 (2010) [2] Yuan et al., Nat. Com. **10**, 5769 (2019) [3] Bistritzer and MacDonald, PNAS **108**, 12233-12237 (2011) [4] X. Lin, D. Tomanek, PRB 98, 081410 (2018)

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